



# SSCT20V11L3

## SSCT20V11L3

1-Line Uni-directional TVS Diode

### ● Description

The SSCT20V11L3 is an uni-directional TVS diode, utilizing leading monolithic silicon technology to provide fast response time and low ESD clamping voltage, making this device an ideal solution for protecting voltage sensitive data and power line. The SSCT20V11L3 complies with the IEC 61000-4-2 (ESD) with  $\pm 30\text{kV}$  air and  $\pm 30\text{kV}$  contact discharge. It is assembled into an ultra-small 1.6x1.0x0.5mm lead-free DFN package. The small size and high ESD surge protection make SSCT20V11L3 an ideal choice to protect cell phone, digital cameras, audio players and many other portable applications.

### ● Features

- ◇ Ultra small package:1.6x1.0x0.5mm
- ◇ Protects one data or power line
- ◇ Working voltage:20V
- ◇ 2-pin leadless package
- ◇ Complies with following standards:
  - IEC61000-4-2(ESD)  $\pm 30\text{Kv}$ (contact), $\pm 30\text{kV}$ (air)
  - IEC61000-4-5(Lightning) 45A(8/20 $\mu\text{s}$ )
- ◇ RoHS Compliant

### ● PIN configuration



Top view



Marking

### ● Applications

- ◇ Mobile Phones
- ◇ Battery Protection
- ◇ Power Line Protection
- ◇ Vbat pin for Mobile Devices
- ◇ Hand Held Portable Applications

### ● Mechanical Characteristics

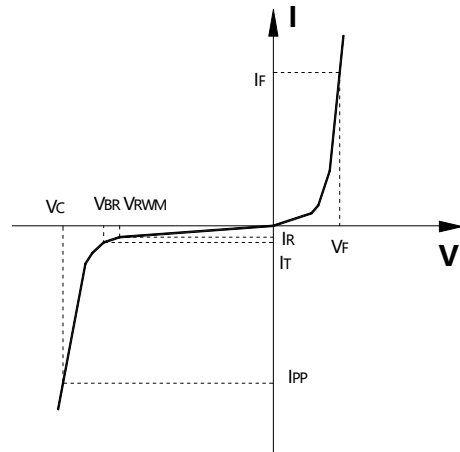
- ◇ Package:DFN1610-2L(1.6x1.0x0.5mm)
- ◇ Case Material: “Green” Molding Compound.
- ◇ UL Flammability Classification Rating 94V-0
- ◇ Moisture Sensitivity: Level 3 per J-STD-020
- ◇ Terminal Connections: See Diagram Below
- ◇ Marking Information: See Below



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## ● Electronic Parameter

Symbol	Parameter
$V_{RWM}$	Peak Reverse Working Voltage
$I_R$	Reverse Leakage Current @ $V_{RWM}$
$V_{BR}$	Breakdown Voltage @ $I_T$
$I_T$	Test Current
$I_{PP}$	Maximum Reverse Peak Pulse Current
$V_C$	Clamping Voltage @ $I_{PP}$
$P_{PPP}$	Peak Pulse Power
$C$	Junction Capacitance



## ● Absolute maximum rating @ $T_A=25^{\circ}C$

Symbol	Parameter	Value	Units
VESD	ESD Rating per IEC61000-4-2:Contact	$\pm 30$	KV
	Air	$\pm 30$	
$P_{PPP}$	Peak Pulse Power (8/20 $\mu$ s)	1500	W
$I_{PP}$	Peak Pulse Current (8/20 $\mu$ s)	45	A
$T_{STG}$	Storage Temperature	-55/+150	$^{\circ}C$
$T_J$	Operating Temperature	-55/+125	$^{\circ}C$

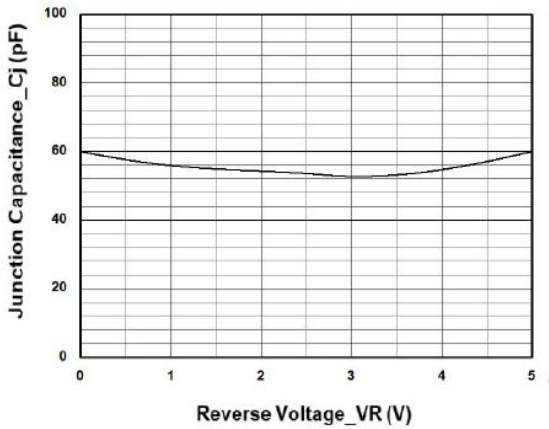
## ● Electrical Characteristics @ $T_A=25^{\circ}C$

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Units
Peak Reverse Working Voltage	$V_{RWM}$	Any I/O to Ground			20	V
Breakdown Voltage	$V_{BR}$	$I_T = 1mA$	22			V
Reverse Leakage Current	$I_R$	$V_{RWM} = 20V,$			1	$\mu A$
Clamping Voltage	$V_{C1}$	$I_{PP} = 20A, t_P = 8/20\mu s$			26	V
Clamping Voltage	$V_{C2}$	$I_{PP} = 45A, t_P = 8/20\mu s$			30	V
Junction Capacitance	$C_J$	$V_R = 0V, f = 1MHz,$		70		pF

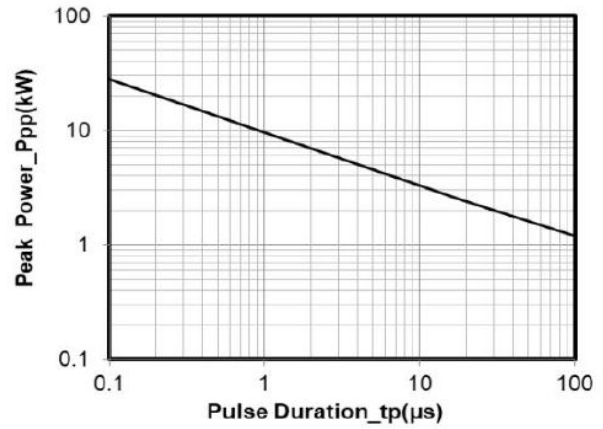


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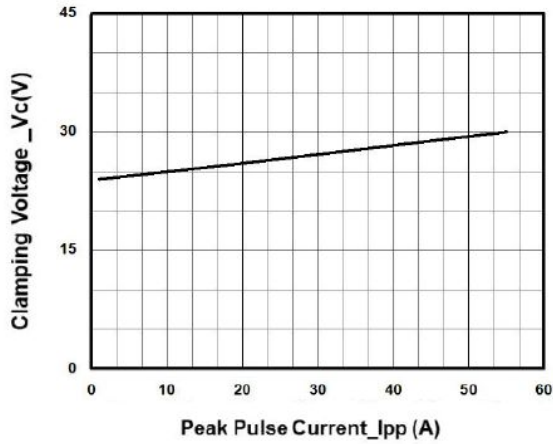
● **Typical Performance Characteristics**( $T_A=25^{\circ}\text{C}$  unless otherwise Specified)



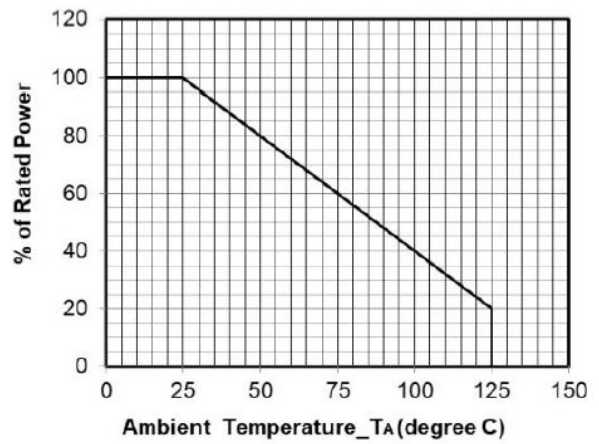
**Junction Capacitance vs. Reverse Voltage**



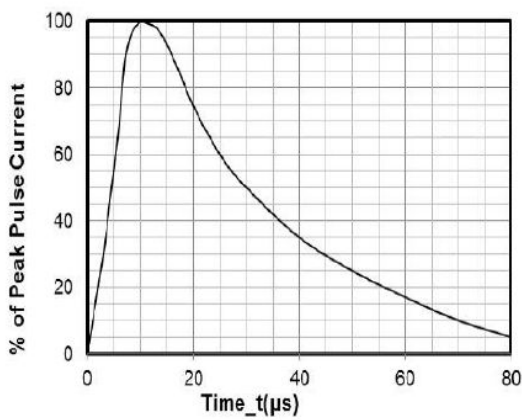
**Peak Pulse Power vs. Pulse Time**



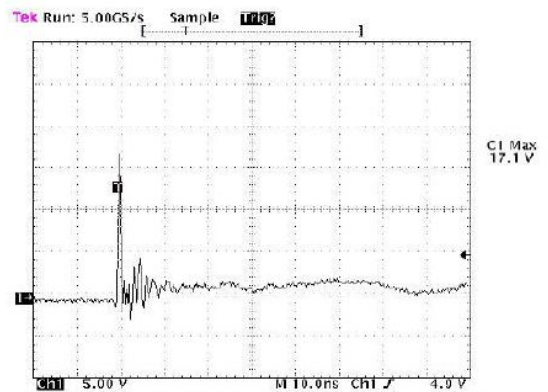
**Clamping Voltage vs. Peak Pulse Current ( $t_p = 8/20\mu\text{s}$ )**



**Power Derating Curve**



**8 X 20μs Pulse Waveform**



Note: Data is taken with a 10x attenuator

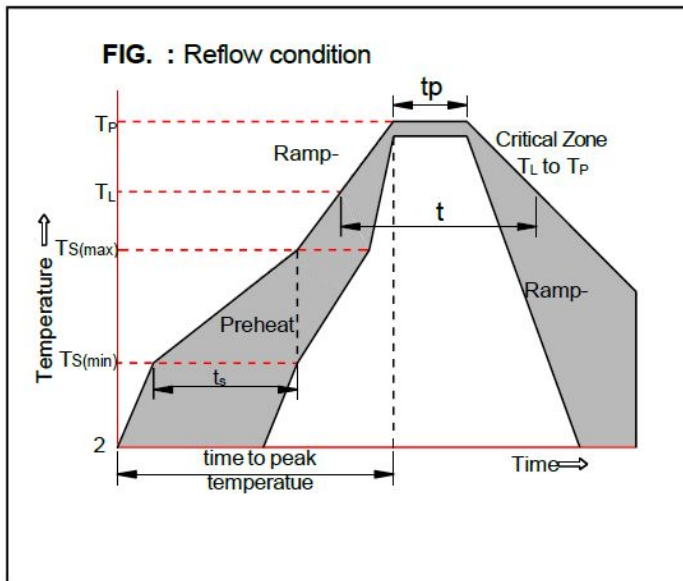
**ESD Clamping Voltage**

**+8 kV Contact per IEC61000-4-2**



- Soldering Parameters**

Reflow Condition		Pb-Free assembly (see as bellow)
Pre Heat	-Temperature Min (Ts(min))	+150°C
	-Temperature Max(Ts(max))	+200°C
	-Time (Min to Max) (ts)	60-180 secs.
Average ramp up rate (Liquid us Temp (TL) to peak)		3°C/sec. Max
Ts(max) to TL - Ramp-up Rate		3°C/sec. Max
Reflow	-Temperature(TL)(Liquid us)	+217°C
	-Temperature(TL)	60-150 secs.
Peak Temp (Tp)		+260(+0/-5)°C
Time within 5°C of actual Peak Temp (tp)		30 secs. Max
Ramp-down Rate		6°C/sec. Max
Time 25°C to Peak Temp (TP)		8 min. Max
Do not exceed		+260°C





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## ● Package Information

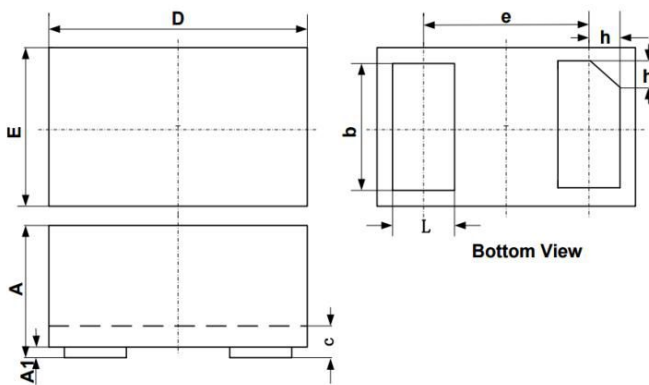
### Ordering Information

Device	Package	Qty per Reel	Reel Size
SSCT20V11L3	DFN1610-2L	3000	7 Inch

### Mechanical Data

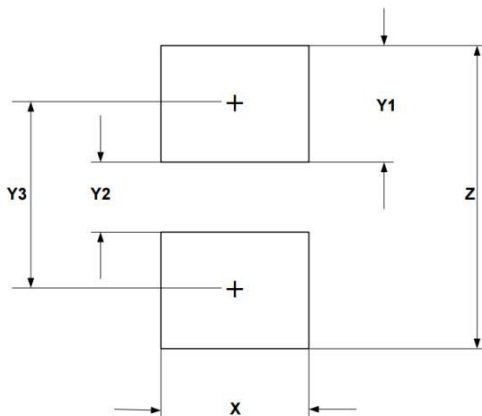
Case: DFN1610-2L

Case Material: Molded Plastic. UL Flammability



SYM	DIMENSIONS					
	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.45	0.50	0.55	0.018	0.020	0.022
A1	0.00	0.02	0.05	0.000	0.001	0.002
b	0.75	0.80	0.85	0.030	0.032	0.034
c	0.10	0.15	0.20	0.004	0.006	0.007
D	1.55	1.60	1.65	0.062	0.064	0.066
e	1.10 BSC			0.044 BSC		
E	0.95	1.00	1.05	0.038	0.040	0.042
L	0.35	0.40	0.45	0.014	0.016	0.018
h	0.15	0.20	0.25	0.006	0.008	0.010

### Suggested Land Pattern



SYM	DIMENSIONS	
	MILLIMETERS	INCHES
X	1.00	0.040
Y1	0.62	0.025
Y2	0.60	0.024
Y3	1.22	0.049
Z	1.85	0.074



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